Perovskite-silicon tandem solar modules with optimised light harvesting

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Supporting Information

Figure S1: Simulated and measured transmittance, reflectance spectra of semi-transparent perovskite solar cell (a) without textured film and (b) with textured film. The spectra of solar cells and solar modules are identical.



Figure S2: Scanning electron microscopy image of the textured film with inverted pyramids.



Figure S3: Effect of refractive index of the index matching layer on shortcircuit current density of perovskite top solar cell and IBC c-Si bottom solar cell with optimised textured film.



Figure S4: Effect of refractive index of index matching layer and thickness of IBC c-Si anti-reflective coating (ARC) on short-circuit current density of IBC c-Si bottom solar cell in tandem configuration with optimally textured perovskite top solar cell.



Figure S5: Impact of inclination angle and base length of inverted pyramidal texture on short-circuit current density of IBC c-Si bottom solar cell with an index matching layer of refractive index 1.5.



Figure S6: Impact of inclination angle and base length of upright pyramidal textures on short-circuit current density (J_{SC}) of IBC c-Si bottom solar cell. Using upright pyramids results in a peak J_{SC} of 14.6 mA/cm², which is lower than the 15.1 mA/cm² for inverted pyramids. The intermediate medium between top and bottom solar cells is air.



Figure S7: Influence of thickness of (a) air gap and (b) refractive index matching layer on the short-circuit current density of the perovskite and IBC c-Si solar cells.



Figure S8: Simulated external quantum efficiency of perovskite top solar cell and IBC c-Si bottom solar cell in tandem configuration in three different cases.



Figure S9: Optical microscopy image of P1, P2, and P3 scribes of the perovskite solar module.



Figure S10: (a) Measured hysteresis scan of stand-alone semi-transparent perovskite solar cell. Semi-transparent perovskite solar module also shows similar hysteresis behavior. **(b)** The semi-transparent perovskite solar cells and modules show stable power output (PCE_{SPO}) during operation at maximum power point.



Figure S11: Histogram representing the spread in stabilized power output (PCE_{SPO}) of semi-transparent perovskite solar cells and modules.



Figure S12: (a) Measured photoluminescence spectrum and (b) Tauc plot of the perovskite absorber. The extracted bandgap is 1.56 eV.

Table S1: Optical analysis of Perovskite-IBC c-Si tandem stack in the reference case (FLAT) and the case with optimised textured film and refractive index matching layer of refractive index 1.5 (TEX + IML). The photocurrent density attributable to various processes was integrated for wavelengths from 300 nm to 1200 nm assuming AM 1.5G irradiance.

		Integrated photocurrent density in mA/cm ²			
	F	FLAT		TEX + IML	
Overall reflection	5.87	(12.7%)	2.20	(4.8%)	
Absorption in glue		-	0.32	(0.7%)	
Absorption in glass	1.63	(3.5%)	1.86	(4.0%)	
Absorption in ITO (front)	1.86	(4.0%)	2.44	(5.3%)	
Absorption in TiO ₂	0.04	(0.1%)	0.04	(0.1%)	
Absorption in CsFAPbIBr	21.40	(46.3%)	22.09	(47.8%)	
Absorption in Spiro-OMeTAD	0.43	(0.9%)	0.54	(1.2%)	
Absorption in ITO (rear)	0.11	(0.2%)	0.14	(0.3%)	
Absorption in c-Si	14.15	(30.6%)	15.86	(34.3%)	
Absorption in c-Si rear contacts	0.77	(1.7%)	0.77	(1.7%)	

Case	Index matching layer refractive index	IBC c-Si ARC thickness (nm)	J _{sc} of IBC c-Si (mA/cm ²)
TEX	1.0	60	15.19
TEX + IML	1.5	60	15.70
Optimal	1.6	40	15.74

Table S2: Simulated short-circuit current density (J_{SC}) of IBC c-Si bottom solar cell for different index matching layers and anti-reflective coating (ARC) thicknesses.

Table S3: Average values of photovoltaic parameters of semi-transparent perovskite solar cell (0.13 cm^2) and IBC c-Si solar cell (4 cm^2) measured under 1000 W/m² AM 1.5G irradiance. The response of the IBC c-Si solar cell in four-terminal configuration is measured with the incident light filtered through a 4 cm² semi-transparent perovskite solar module. The reported power conversion efficiencies are stabilised power outputs (PCE_{SPO}) tracked at maximum power point for 10 minutes.

	Device	J _{sc} (mA/cm²)	V _{oc} (V)	FF (%)	Aperture PCE _{sPO} (%)
Stand alone	Perovskite	21.8 ± 0.1	1.02 ± 0.02	73.7 ± 1.4	16.7 ± 0.3
	IBC c-Si	41.3 ± 0.04	0.691 ± 0.001	80.6 ± 0.1	23.0 ± 0.01
	Perovskite	21 8 + 0 1	1 02 + 0 02	736+14	167+03
	FEIOVSKILE	21.0 ± 0.1	1.02 ± 0.02	75.0 ± 1.4	10.7 ± 0.5
FLAT	IBC c-Si	14.1 ± 0.06	0.673 ± 0.002	81.7 ± 0.1	7.8 ± 0.02
	Tandem				24.5 ± 0.3
	Perovskite	22.0 ± 0.1	1.02 ± 0.01	73.6 ± 1.4	16.8 ± 0.2
ΤΕΧ	IBC c-Si	15.1 ± 0.01	0.674 ± 0.001	81.7 ± 0.1	8.3 ± 0.04
	Tandem				25.1 ± 0.2
TEX	Perovskite	22.0 ± 0.1	1.01 ± 0.02	73.4 ± 1.3	16.7 ± 0.3
+ IML	IBC c-Si	15.6 ± 0.03	0.674 ± 0.002	81.7 ± 0.1	8.6 ± 0.04
	Tandem				25.3 ± 0.3